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Electronic Supplementary Information

Modelling the Activity Trend of Hydrogen Oxidation Reaction under Constant Potential Conditions

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1. Density functional theory calculations

For all density functional theory (DFT) calculations, the Vienna Ab-initio Simulation Package (VASP)^{1, 2} was utilized, employing the Projector Augmented-Wave (PAW) method^{3, 4} to model electron-ion interactions. To approximate exchange and correlation energies, the Perdew-Burke Ernzerhof (PBE) functional⁵ was utilized. A cutoff energy of 400 eV was used, and a convergence criterion for forces of 0.05 eV/Å was applied. A minimum vacuum height of 13 Å was imposed to prevent interactions between periodic structures. The energy associated with the most stable configuration was used in the calculation of free energy for various adsorbates, and the nudged elastic band (NEB)⁶ method was employed to locate transition states.

Simulations conducted under constant potential conditions were performed using the grand-canonical density functional theory (GC-DFT)⁷ method within the JDFTx software package.⁸ The PBE functional was also used here, and an energy cutoff of 14.7 Hartree (400 eV) was employed. Brillouin zone sampling utilized the Monkhorst-Pack scheme¹. To account for solvation effects, the implicit solvent model CANDLE⁹ was employed, with the implicit solvent environment¹⁰⁻¹³ providing compensating charges to maintain overall charge neutrality within the unit cell. The parameters were configured for a solvent environment containing 1 M fluoride anions and 1 M sodium cations in an aqueous solution. Additionally, we opted to include two explicit water molecules in the model. On one hand, the implicit solvent model represents the solvent as a continuous medium, simplifying the system complexity and improving computational efficiency. On the other hand, incorporating a small number of explicit water molecules provides a more detailed and accurate description, especially around active sites or key reaction sites, thereby balancing efficiency and accuracy.¹⁴⁻¹⁶

2. Adsorption energy calculations

The free energy of hydrogen adsorption $({}^{H_2 + 2 * \rightarrow 2H^*})$ was calculated using the following equation:

$$\Delta G_{H^*} = \frac{1}{2} E_{slab+2H^*} - E_{H_2} - E_{slab} + TS_{H_2}$$
(S1)

where $E_{\text{slab+2H*}}$ and E_{slab} are the energies of the slab with adsorbed 2^{H^*} and the clean slab, respectively. E_{H_2} denotes the energy of gaseous H_2 , while S_{H_2} signifies the entropy of H_2 at 298.15 K, which is 1.36 meV/K.

The activity descriptor of the catalyst should be formulated in a manner that is both straightforward and computationally efficient. We begin by considering the OH

$$H_2O + * \rightarrow OH^* + \frac{1}{2}H_2$$

adsorption process:

Based on this equation, the OH adsorption energy can be calculated using the following expression:

$$\Delta G_{OH^*} = E_{slab + OH^*} + \frac{1}{2}G_{H_2} - G_{H_2O} - E_{slab}$$
(S2)

where ${}^{E}_{slab+OH^*}$ is the total energy of the slab with absorbed OH^{*}, while ${}^{G}_{H_2}$ and ${}^{G}_{H_2O}$ are the Gibbs free energy of H₂(g) and H₂O(l), respectively, which can be calculated using the following equations:

$$G_{H_2} = E_{H_2} - TS_{H_2}$$
$$G_{H_20} = E_{H_20} - TS_{H_20}$$

In the context of this straightforward model, the adsorption process of OH does not involve electron transfer, resulting in exceptionally high computational efficiency for determining the adsorption energy.

By constructing a thermodynamic cycle, we can derive the following relationships:

$$\Delta G_{OH^{-}} = \Delta G_{OH^{*}} + G_{H_2O} - \frac{1}{2}G_{H_2} - G_{OH^{-}} + G_{e^{-}}$$
(S3)

therefore, we can have

$$\Delta G_{OH^-} - \Delta G_{OH^*} = G_{H_2O} - \frac{1}{2}G_{H_2} - G_{OH^-} + G_{e^-} = 0.83 \ eV + eU$$
, according to the standard Gibbs energy of formation of H₂O, H₂ and OH⁻ at 298.15 K. When the

electrode potentials are at 0 V and 0.2 V vs. RHE, we can derive: $\Delta G_{OH^{-}} - \Delta G_{OH^{*}} = 0.83 \ eV_{and} \ \Delta G_{OH^{-}} - \Delta G_{OH^{*}} = 1.03 \ eV_{, respectively.}$

3. Microkinetic simulation

Previous researchers have extensively demonstrated that microkinetic model can help determine the rates of specific steps of catalytic reactions, including reactant adsorption, activation, and the formation of reaction intermediates.¹⁶⁻¹⁹ We employed a similar approach to perform Microkinetic simulation. The rate-determining step (RDS) would be one of the steps within the Tafel step, Indirect Volmer step or Direct Volmer step.

$$\frac{1}{2}H_{2} + * \rightarrow H^{*}$$
(1)

$$H^{*} + OH^{*} \rightarrow H_{2}O + 2 *$$
(2)

$$H^{*} + OH^{-} \rightarrow H_{2}O + e^{-} + *$$
(3)

An additional OH⁻ adsorption process is involved in Indirect Volmer step:

$$OH^- + * \to OH^* + e^- \tag{4}$$

When step (1) is rate-determining in the reaction, other steps are considered quasiequilibrated, then we can have

$$r = r_{1} = k_{1}\theta^{*}_{, \text{ and }}k_{1} = Aexp(-\frac{\Delta G_{TS}^{H}}{RT})$$
$$\theta^{*} = \frac{K_{4}K_{2}}{1 + K_{4}K_{2} + K_{4}^{2}K_{2}}, K_{4} = \exp\left(-\frac{\Delta G_{OH}^{-}}{RT}\right), K_{2} = \exp\left(\frac{\left(\Delta G_{H}^{*} + \Delta G_{OH}^{-}\right)}{RT}\right)$$

It should be noted that step (2) and step (3) are competing in the system, therefore one can consider the rate-determining step being either step (2) or step (3).

When step (2) is rate-determining, we can have

$$r = r_{2} = k_{2}\theta_{H}\theta_{OH, \text{ and}} \qquad k_{2} = Aexp\left(\frac{\Delta G_{H^{*}} + \Delta G_{OH^{-}}}{RT}\right)$$

$$\theta_{H} = \sqrt{p/p^{0}}K_{1}\theta^{*}, \quad \theta_{OH} = cK_{4}\theta^{*}, \quad K_{1} = exp\left(-\frac{\Delta G_{H^{*}}}{RT}\right), \quad K_{4} = \exp\left(-\frac{\Delta G_{OH^{-}}}{RT}\right),$$

$$\theta^{*} = \frac{1}{1 + exp\left(-\frac{\Delta G_{H^{*}}}{RT}\right) + \exp\left(-\frac{\Delta G_{OH^{-}}}{RT}\right)}$$

Similarly, when step (3) is rate-determining, step (1) is considered quasi-equilibrated, the following relations can be obtained:

$$r = r_3 = k_3 \theta_{H, \text{ and}} k_3 = Aexp\left(-\frac{\Delta G_{TS}}{RT}\right), \theta_H = \frac{K_1}{1 + K_1}, K_1 = Aexp\left(-\frac{\Delta G_{H*}}{RT}\right)$$

In the above expressions, k_i and K_i indicate the forward rate constant and equilibrium constant of step i, respectively. p (1 bar in the current work) and θ indicates the pressure and intermediates coverage, respectively. p^0 represents the standard pressure, i.e., 1 bar. c is the molar concentration of OH⁻, which is 0.1 mol/L in the current work, corresponding to pH = 13. ΔG_{TS}^{H} and ΔG_{TS} represent the activation energies of the Tafel and Volmer steps, respectively. ΔG_{H^*} and ΔG_{OH^-} represent the adsorption energies of H and OH⁻, respectively. The corresponding rate constants (k) and coverage(θ) can be calculated as functions of H adsorption energy ($G_{H^*}^{H^*}$) and OH adsorption energy ($\Delta G_{OH^*}^{H^*}$), with the specific functional relationships provided in Figure 3 of the main

text. A is the pre-exponential factor which is $\frac{k_B T}{h}$, k_B and h represent Boltzmann and Planck constant. The overall reaction rate is given by min(r₁, max(r₂, r₃)). The basic idea is that the overall rate should be equal to the rate of the rate determining step, which shows the lowest reaction rate in the whole reaction pathway and the method has been used in the microkinetic analyses of electrocatalytic reactions.^{16, 17, 20}

	$\Delta G_{ m H^*/eV}$	$\Delta G_{ m OH*}/ m eV$
Cu(111)	-0.03	0.90
Ag(111)	0.40	0.95
Au(111)	0.32	1.55
Pt(111)	-0.24	1.11
Pd(111)	-0.51	0.70
Ir(111)	-0.17	0.79
Rh(111)	-0.32	0.34
Ru(0001)	-0.41	-0.14
PtRu	-0.30	0.41
PdNi	-0.28	0.13
SnRu	-0.39	0.05
RuNi	-0.45	-0.21
PtRu(alloy)	-0.26	0.05
GaRu	-0.43	-0.17
PdIr2	-0.33	0.45
IrRu2	-0.34	0.13
Ir_1Ru_1	-0.41	-0.03
PtCu	0.02	1.34
PtAu	-0.52	0.44
NiCu	-0.37	0.03
PtRu	-0.30	0.41
WNi ₄	-0.30	-1.31
MoNi ₄	-0.29	-0.88
$1 \mathrm{OH}_{\mathrm{W}}$	-0.38	-1.25
$1 OH_{Mo}$	-0.37	-0.41
$2\mathrm{OH}_{\mathrm{W}}$	-0.49	-0.42
$2OH_{Mo}$	-0.48	0.24

Table S1. Adsorption free energies of H and OH on different catalyst surfaces.

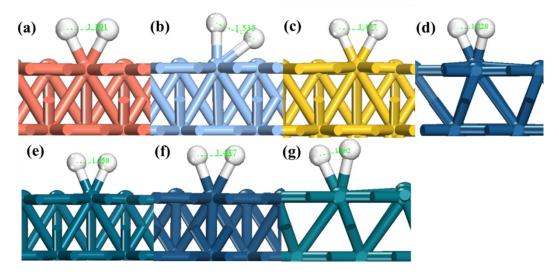


Figure S1. Structure of H_2 dissociation step transition state on (a) Cu(111), (b) Ag(111), (c)Au (111), (d) Pt(111), (e) Pd(111), (f) Ir (111) and (g) Rh(111) surfaces. White balls are hydrogen atoms.

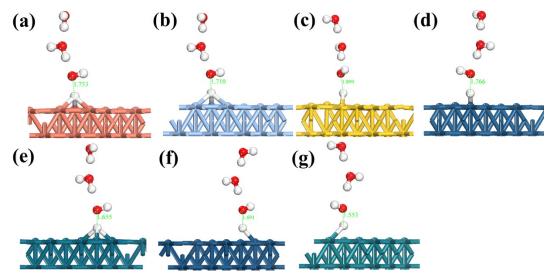


Figure S2. Structure of the Direct Volmer step transition state on (a) Cu(111), (b) Ag(111), (c)Au (111), (d) Pt(111), (e) Pd(111), (e) Ir (111) and (g) Rh(111) surfaces. Red and white balls are oxygen and hydrogen atoms, respectively.

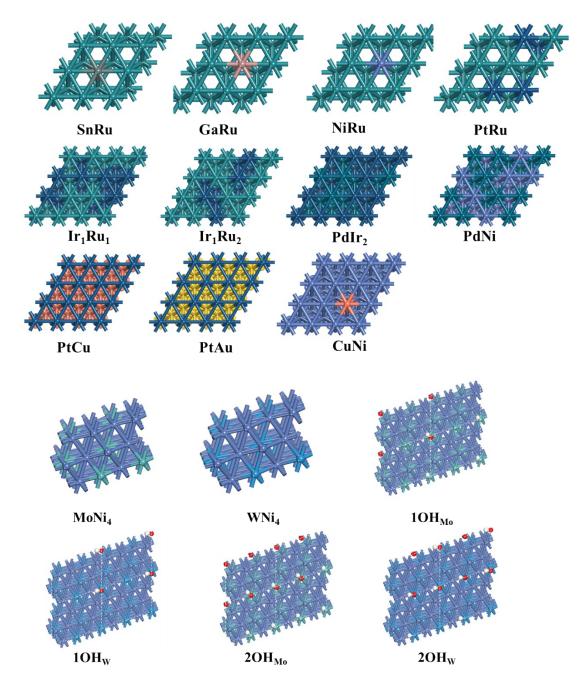


Figure S3. Structure of alloy catalysts.

5. Input file

Our input files include three types: the first type is the DFT calculation for structural optimization using VASP, the second type uses NEB for transition state search, and the third type conducts simulations under constant potential conditions using JDFTx. Below is the example input file we provided:

#DFT input file

general:
System = Cu
ISTART=0
ISPIN=1
ENCUT = 400 eV
PREC=high
ISIF=2
IBRION=2
POTIM=0.2
ALGO=Fast
EDIFFG=-0.05
ISMEAR = 1; SIGMA = 0.10
NSW = 2000
NSW = 2000 LREAL=A
LREAL=A
LREAL=A LWAVE =.False.
LREAL=A LWAVE =.False. GGA=PE
LREAL=A LWAVE =.False. GGA=PE NELM=200
LREAL=A LWAVE =.False. GGA=PE NELM=200 NSIM=4
LREAL=A LWAVE =.False. GGA=PE NELM=200 NSIM=4 LCHARG = F

#NEB input file general: System = CuISTART=0 ISPIN=1 ENCUT = 400 eVPREC=high ISIF=2 IBRION=3 #2sructure-opt 3-neb POTIM=0 #IALGO = 48ALGO=Fast EDIFF=1E-7 EDIFFG=-0.03 ISMEAR = 1; SIGMA = 0.10NSW = 2000LREAL=A LWAVE =.False. GGA=PE NELM=200 NSIM=4 LCHARG = FISYM = 0LSOL = .TRUE. $EB_K = 80$ ICHAIN=0 IPOT=1 IMAGES=7 SPRING=-5

LCLIMB=.False.

#JDFTx inputfile

#--- Pseudopotentials ---ion-species GBRV/\$ID_pbe.uspp #GBRV family elec-cutoff 14.7 #Ecuts for psi and rho elec-ex-corr gga-PBE include in.lattice include in.ionpos coulomb-truncation-ion-margin 4 ionic-minimize \setminus nIterations 2000 \ energyDiffThreshold $0 \setminus$ knormThreshold 1e-3 #Threshold on RMS cartesian force #--- Electronic ---kpoint-folding 3 3 1 elec-smearing MP1 0.00184 target-mu -0.1349 #-0.1422 for 0.2V #--- Fluid ---fluid LinearPCM pcm-variant CANDLE fluid-solvent H2O fluid-cation Na+ 0.1 fluid-anion F-0.1 dump-name opt.\$VAR dump End IonicPositions dump End ElecDensity

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